



TEA1792T

GreenChip synchronous rectifier controller

Rev. 2 — 9 July 2012

Product data sheet

1. General description

The TEA1792T is a member of the new generation of Synchronous Rectifier (SR) controller ICs for switched mode power supplies. Its high level of integration allows the design of a cost-effective power supply with a very low number of external components.

The TEA1792T is a controller IC dedicated to synchronous rectification on the secondary side of discontinuous conduction mode and quasi-resonant flyback converters.

The TEA1792T is fabricated in a Silicon-On-Insulator (SOI) process.

2. Features and benefits

2.1 Distinctive features

- Accurate synchronous rectification functionality
- Wide supply voltage range (8.5 V to 38 V)
- High level of integration, resulting in a very low external component count
- High driver output voltage of 10 V to drive all MOSFET brands to the lowest R_{DSon}
- Selectable regulation level for driver stage

2.2 Green features

- Low current consumption
- High system efficiency from no load to full load

2.3 Protection features

- UnderVoltage Protection (UVP)

3. Applications

- The TEA1792T is intended for adapters. The device can also be used in all other discontinuous conduction mode systems and quasi-resonant flyback systems that demand a highly efficient and cost-effective solution.

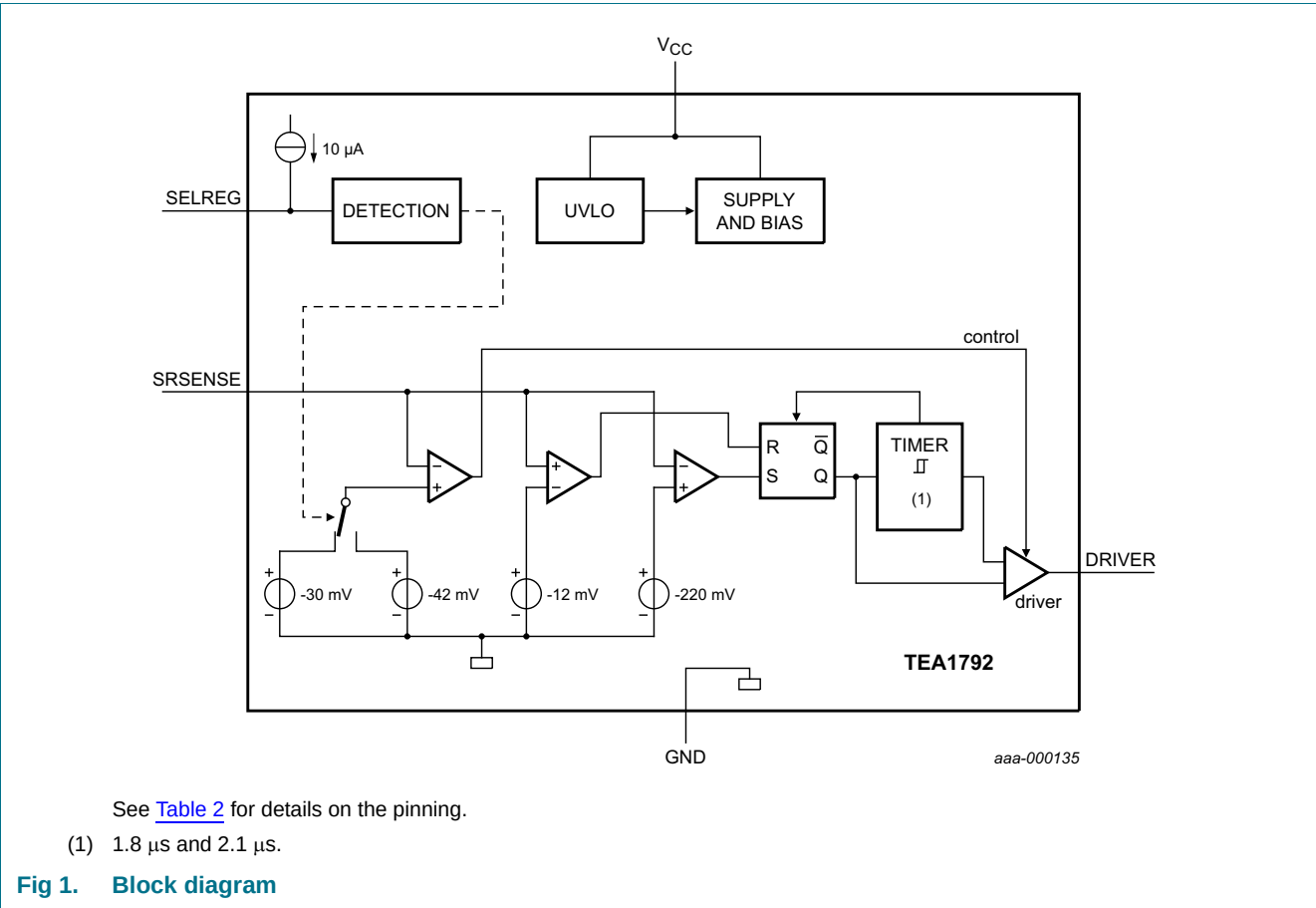


4. Ordering information

Table 1. Ordering information

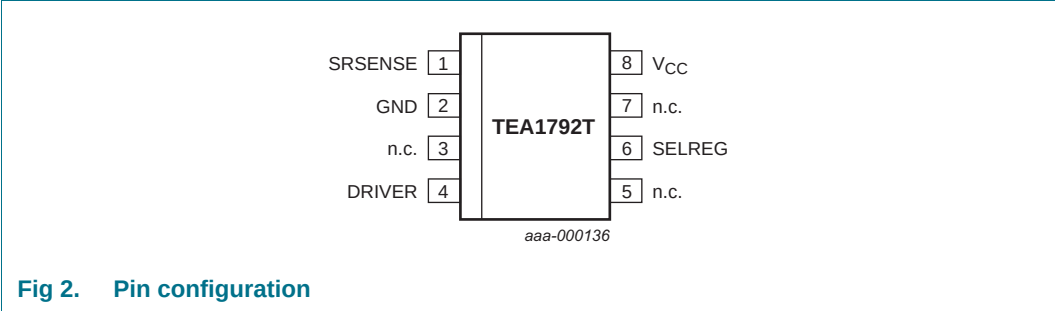
Type number	Package		Version
	Name	Description	
TEA1792T/N1	SO8	plastic small outline package; 8 leads; body width 3.9 mm	SOT96-1

5. Block diagram



6. Pinning information

6.1 Pinning



6.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
SRSENSE	1	synchronous timing input
GND	2	ground
n.c.	3	not connected
DRIVER	4	driver output for SR MOSFET
n.c	5	not connected
SELREG	6	selection input for driver regulation level
n.c.	7	not connected
V _{CC}	8	supply voltage

7. Functional description

7.1 Introduction

The TEA1792T is the controller for synchronous rectification used in discontinuous conduction mode and quasi-resonant flyback converters.

7.2 Start-up and UnderVoltage LockOut (UVLO)

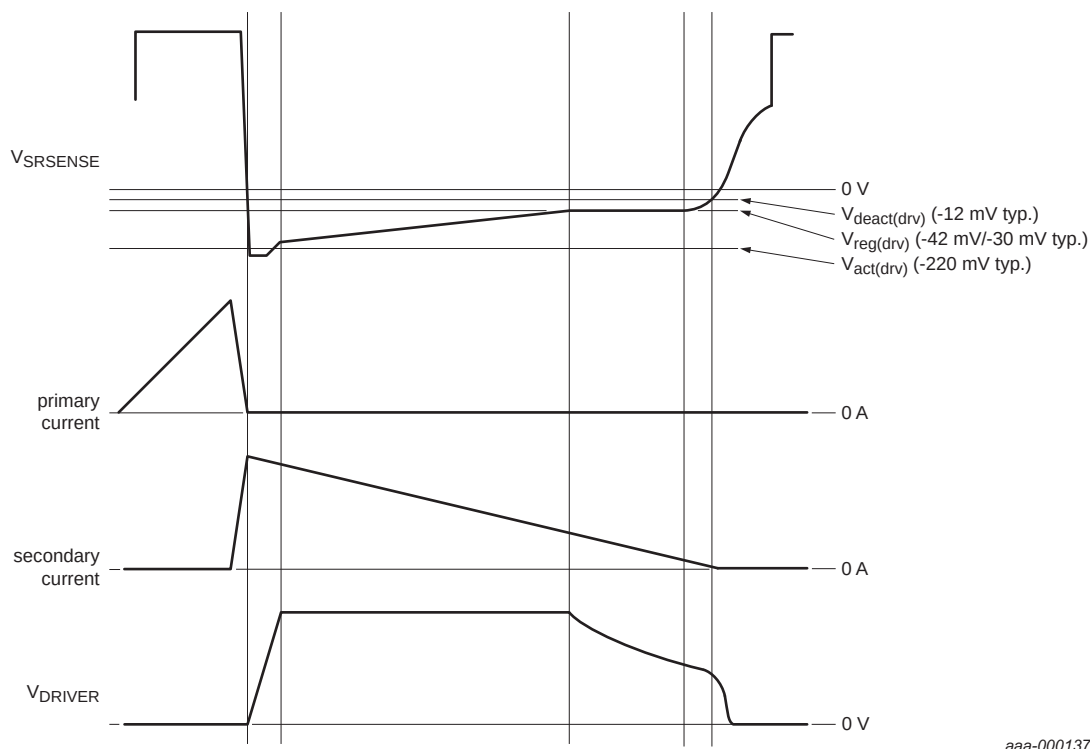
The IC leaves the undervoltage lockout state and activates the synchronous rectifier circuitry when the voltage on the V_{CC} pin is above 8.5 V (typical). When the voltage drops below 8.0 V (typical), the undervoltage lockout state is entered again and the SR driver output is actively kept low.

7.3 Synchronous rectification

After a negative voltage lower than $V_{act(drv)}$ (–220 mV typical) is sensed on the SRSENSE pin, the driver output voltage is driven HIGH. Then the external MOSFET is switched on. When the SRSENSE voltage rises to $V_{reg(drv)}$ (–42 mV/–30 mV), the driver output voltage is regulated to maintain the $V_{reg(drv)}$ on the SRSENSE pin. When the SRSENSE voltage is above the $V_{deact(drv)}$ level (–12 mV typical), the driver output is pulled to ground.

After switch-on of the SR MOSFET, the input signal on the SRSENSE pin is blanked during the $t_{act(sr)(min)}$ (1.8 μ s typical). This action eliminates false switch-off due to high frequency ringing at the start of the secondary stroke.

When the voltage on the SRSENSE pin is $V_{reg(drv)}$, the driver output voltage is reduced. This reduction enables the external power switch to be switched off quickly when the current through the switch reaches zero. The zero current switch-off removes the need for a separate Standby mode to maintain high efficiency during the no-load operation. The zero current is detected by sensing a $V_{deact(drv)}$ (–12 mV typical) level on the SRSENSE pin (see [Figure 3](#)).



aaa-000137

Fig 3. Synchronous rectification signals

The level of the driver regulation voltage $V_{\text{reg(drv)}}$ can be selected using the SELREG pin. When this SELREG pin is grounded, the typical $V_{\text{reg(drv)}}$ equals -42 mV . When the SELREG pin is left open, the $V_{\text{reg(drv)}}$ level equals -30 mV .

Internally, the SELREG pin has a pull-up current source of $10\text{ }\mu\text{A}$. When this pin is short circuited to ground, the pin selects the lowest $V_{\text{reg(drv)}}$. If the pin is left open, the highest $V_{\text{reg(drv)}}$ value is selected.

If the secondary stroke of the flyback converter is shorter than $t_{\text{act(sr)(min)}}$ short time ($1.8\text{ }\mu\text{s}$ typical), the driver output is disabled. This action guarantees stable operation for very low duty cycles. When the secondary stroke increases above $t_{\text{act(sr)(min)}}$, long time ($2.1\text{ }\mu\text{s}$ typical), the driver output is again enabled.

7.4 Supply management

All internal reference voltages are derived from a temperature compensated, on-chip band gap circuit.

7.5 Driver

The driver circuit to the external power MOSFET gate has a typical source capability of 400 mA and a typical sink capability of 2.7 A . These capabilities permit fast switch-on and switch-off of the power MOSFET for efficient operation. The source stage is coupled to the timer (see [Figure 1](#)). When the timer has finished, the source capability is reduced to a small current (5 mA typical) capable of keeping the driver output voltage at its level.

The output voltage of the driver is limited to 10 V (typical). This high output voltage drives all MOSFET brands to the minimum on-state resistance.

During start-up conditions ($V_{CC} < V_{startup}$) and undervoltage lockout the driver output voltage is actively pulled low.

8. Limiting values

Table 3. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). All voltages are measured with respect to ground (pin 2); positive currents flow into the chip. The voltage ratings and current ratings are valid provided the other ratings are not violated.

Symbol	Parameter	Conditions	Min	Max	Unit
Voltages					
V_{CC}	supply voltage	continuous	-0.4	+38	V
$V_{SRSENSE}$	voltage on pin SRSENSE	continuous	-	120	V
V_{SELREG}	voltage on pin SELREG	continuous	-0.4	+5	V
Currents					
I_{DRIVER}	current on pin DRIVER	duty cycle < 10 %	-0.8	+3	A
$I_{SRSENSE}$	current on pin SRSENSE		-3	-	mA
General					
P_{tot}	total power dissipation	$T_{amb} < 80\text{ °C}$	-	0.45	W
T_{stg}	storage temperature		-55	+150	°C
T_j	junction temperature		-40	+150	°C
V_{ESD}	electrostatic discharge voltage	human body model; JEDEC Class 2; all pins	[1] -2	+2	kV
		charged device model; JEDEC Class 3; all pins	-500	+500	V

[1] Equivalent to discharging a 100 pF capacitor through a 1.5 kΩ series resistor.

9. Thermal characteristics

Table 4. Thermal characteristics

Symbol	Parameter	Conditions	Typ	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	JEDEC test board	157	K/W
$R_{th(j-c)}$	thermal resistance from junction to case	JEDEC test board	90	K/W

10. Characteristics

Table 5. Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$; $V_{CC} = 20\text{ V}$; all voltages are measured with respect to ground (pin 2); currents are positive when flowing into the IC; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Supply voltage management (pin V _{CC})						
V _{startup}	start-up voltage		8.2	8.5	8.8	V
V _{hys}	hysteresis voltage		[1] 0.35	0.5	0.65	V
I _{CC(oper)}	operating supply current	V _{CC} = 8 V (V _{CC} < V _{startup})	0.2	0.25	0.4	mA
		under normal operation; no load on pin DRIVER	0.8	1	1.2	mA
Synchronous rectification sense input (pin SRSENSE)						
V _{act(drv)}	driver activation voltage		−260	−220	−180	mV
V _{reg(drv)}	driver regulation voltage	resistance between pins SELREG and GND < 15 kΩ	−55	−42	−30	mV
		resistance between pins SELREG and GND > 700 kΩ	−38	−30	−22	mV
V _{deact(drv)}	driver deactivation voltage		-	−12	-	mV
t _{d(act)(drv)}	driver activation delay time		50	75	100	ns
t _{act(sr)(min)}	minimum synchronous rectification active time	short time	1.3	1.8	2.3	μs
		long time	1.6	2.1	2.6	μs
I _{o(SELREG)}	output current on pin SELREG	V _{SELREG} = 2.5 V	−12	−10	−8	μA
Driver (pin DRIVER)						
I _{source}	source current	V _{CC} = 15 V; voltage on pin DRIVER = 2 V				
		during minimum synchronous rectification time	−0.45	−0.4	−0.35	A
		minimum synchronous rectification time has ended	−6	−5	−4	mA
I _{sink}	sink current	V _{CC} = 15 V				
		voltage on pin DRIVER = 2 V	1	1.4	-	A
		voltage on pin DRIVER = 9.5 V	2.2	2.7	-	A
V _{o(max)}	maximum output voltage	V _{CC} = 15 V	9	10	12	V

[1] The V_{CC} stop voltage is $V_{startup} - V_{hys}$.

11. Application information

A switched mode power supply with the TEA1792T consists of a primary side discontinuous conduction mode flyback controller, a transformer and an output stage with a feedback circuit. A MOSFET (Q_{sec}) is used for low conduction losses in the output state. The TEA1792T controls this MOSFET.

The timing for the synchronous rectifier switch is derived from the voltage sensed on the SRSENSE pin. The resistor in the SRSENSE connection protects the TEA1792T from excessive voltages. The R_{SRSENSE} resistor is typically 1 k Ω . Higher values can impair correct timing, lower values do not provide sufficient protection.

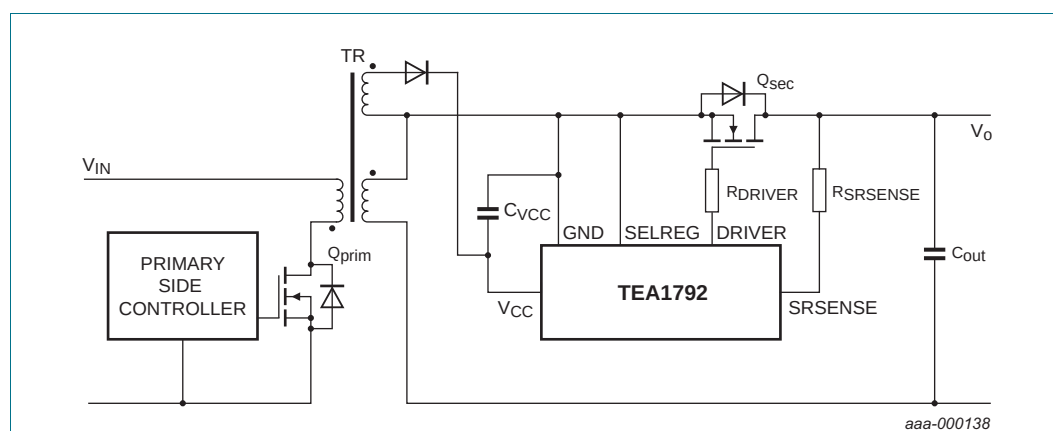


Fig 4. Application diagram high side rectification

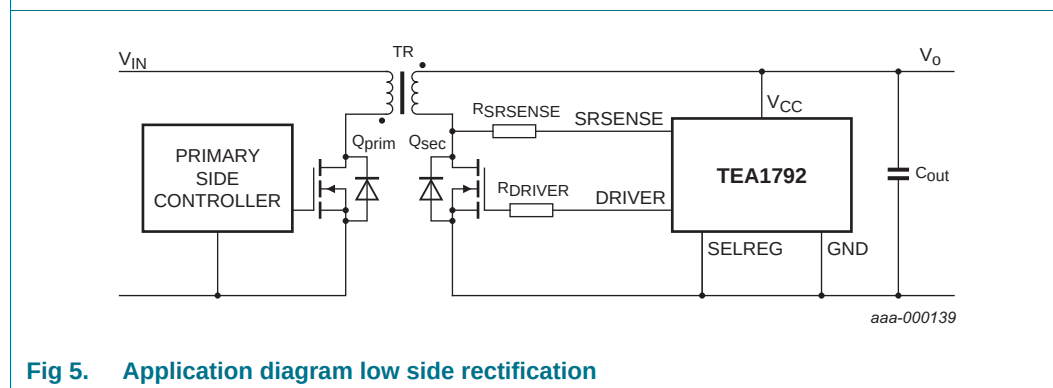
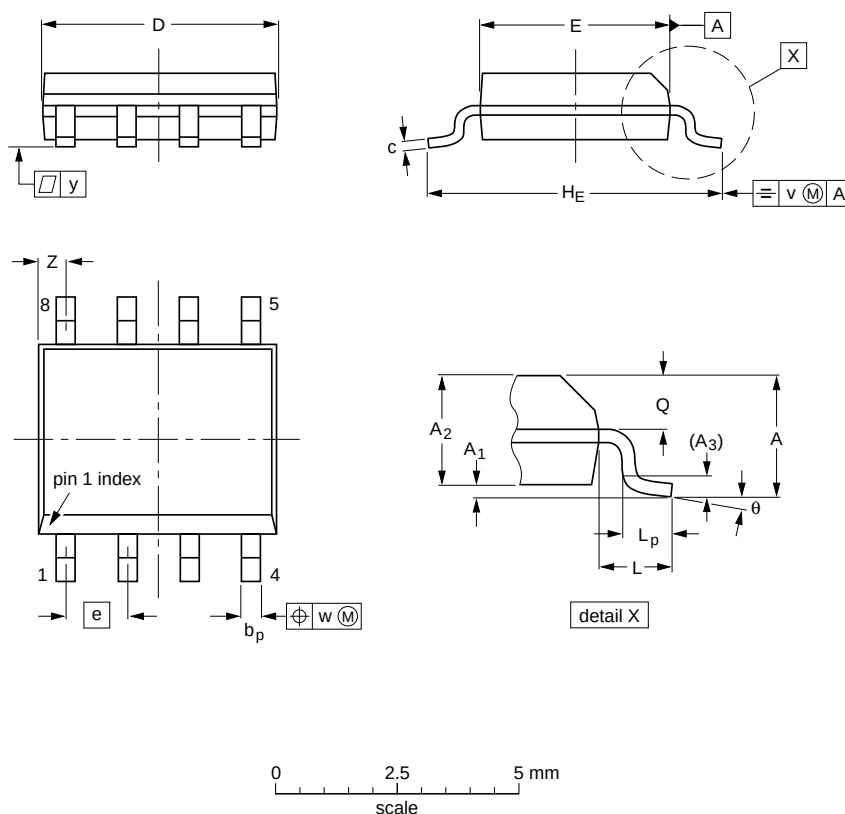


Fig 5. Application diagram low side rectification

12. Package outline

SO8: plastic small outline package; 8 leads; body width 3.9 mm

SOT96-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A _{max.}	A ₁	A ₂	A ₃	b _p	c	D ⁽¹⁾	E ⁽²⁾	e	H _E	L	L _p	Q	v	w	y	Z ⁽¹⁾	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	5.0 4.8	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8° 0'
inches	0.069	0.010 0.004	0.057 0.049	0.01	0.019 0.014	0.0100 0.0075	0.20 0.19	0.16 0.15	0.05	0.244 0.228	0.041	0.039 0.016	0.028 0.024	0.01	0.01	0.004	0.028 0.012	

Notes

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.
2. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT96-1	076E03	MS-012				99-12-27 03-02-18

Fig 6. Package outline SOT96-1 (SO8)

13. Revision history

Table 6. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
TEA1792T v.2	20120709	Product data sheet	-	TEA1792T v.1.1
TEA1792T v.1.1	20120126	Objective data sheet	-	TEA1792T v.1
TEA1792T v.1	20110816	Objective data sheet	-	-

14. Legal information

14.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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16. Contents

1	General description	1
2	Features and benefits	1
2.1	Distinctive features	1
2.2	Green features	1
2.3	Protection features	1
3	Applications	1
4	Ordering information	2
5	Block diagram	2
6	Pinning information	3
6.1	Pinning	3
6.2	Pin description	3
7	Functional description	4
7.1	Introduction	4
7.2	Start-up and UnderVoltage LockOut (UVLO)	4
7.3	Synchronous rectification	4
7.4	Supply management	5
7.5	Driver	5
8	Limiting values	6
9	Thermal characteristics	6
10	Characteristics	7
11	Application information	8
12	Package outline	9
13	Revision history	10
14	Legal information	11
14.1	Data sheet status	11
14.2	Definitions	11
14.3	Disclaimers	11
14.4	Trademarks	12
15	Contact information	12
16	Contents	13

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